

LatticePower @ CSP-1919



Product Describe:

CSP 1919 is a High-Power 4W LED of LatticePower. Through the latest Chip manufacturing technology, it contains many features as high luminous efficiency, resistance to high current and low thermal resistance etc.

Applications:

Automobile、Indoor and Outdoor lighting

Features

- According to the ANSI standard colour gamut
- Compatible with SMT
- Size: 1.90mm×1.90 mm×0.29mm
- Typical Color Temperature and Luminous Flux: 5700K 295 lm@700ml 25 °C/Ra70
- Viewing Angle: 120 °
- Chip: Sapphire Flip Chip

<http://www.latticepower.com/>

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Jiangxi LatticePower Corporation

Jiangxi Nanchang High-tech Zone Aixi Lake North road No. 699

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Applications:

Indoor and Outdoor lighting

Automotive lighting

Flash-lighting



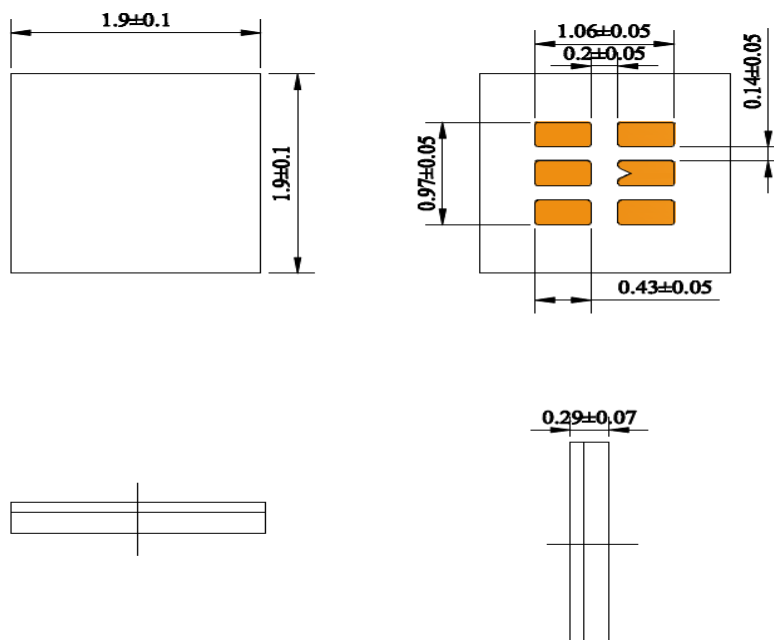
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Product Size



Note: Please strictly refer to the positive and negative of the product

Unit: mm.

Electro Characteristics (T solder pad =25 °C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	conditions
Luminous Flux	Φ	270	295	330	lm	IF=700mA & 25 °C
Forward Voltage	VF	2.9	3.0	3.2	V	
Forward Current	IF		700	1200	mA	
Reverse Voltage	VR			5	V	
Colour TEMP	CCT		5700		K	
CRI	Ra		70			
Viewing Angle	2 θ 1/2		120		°	
Thermal Resistance			0.7		°C/W	
Human Body Model	ESD		2000		V	
Juntion TEMP	Tj			135	°C	

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Luminous Flux Characteristics (T solder pad = 25 °C)

Color TEMP	CCT		Luminous Flux@25 °C					
	Min.	Max.	350mA		700mA		1000mA	
			Flux	Efficiency	Flux	Efficiency	Flux	Efficiency
Cold White	5000K	8000K	162	158	295	138	384	124

Note: ① It maintains a tolerance of $\pm 7\%$ on luminous flux measurements.

② Flux and Efficiency' s unit is Lm and Lm/W.

Product Code

19 - 2A - PB - 70 - B3
 | | | | |
 Product Type Colour Area Brightness CRI VF

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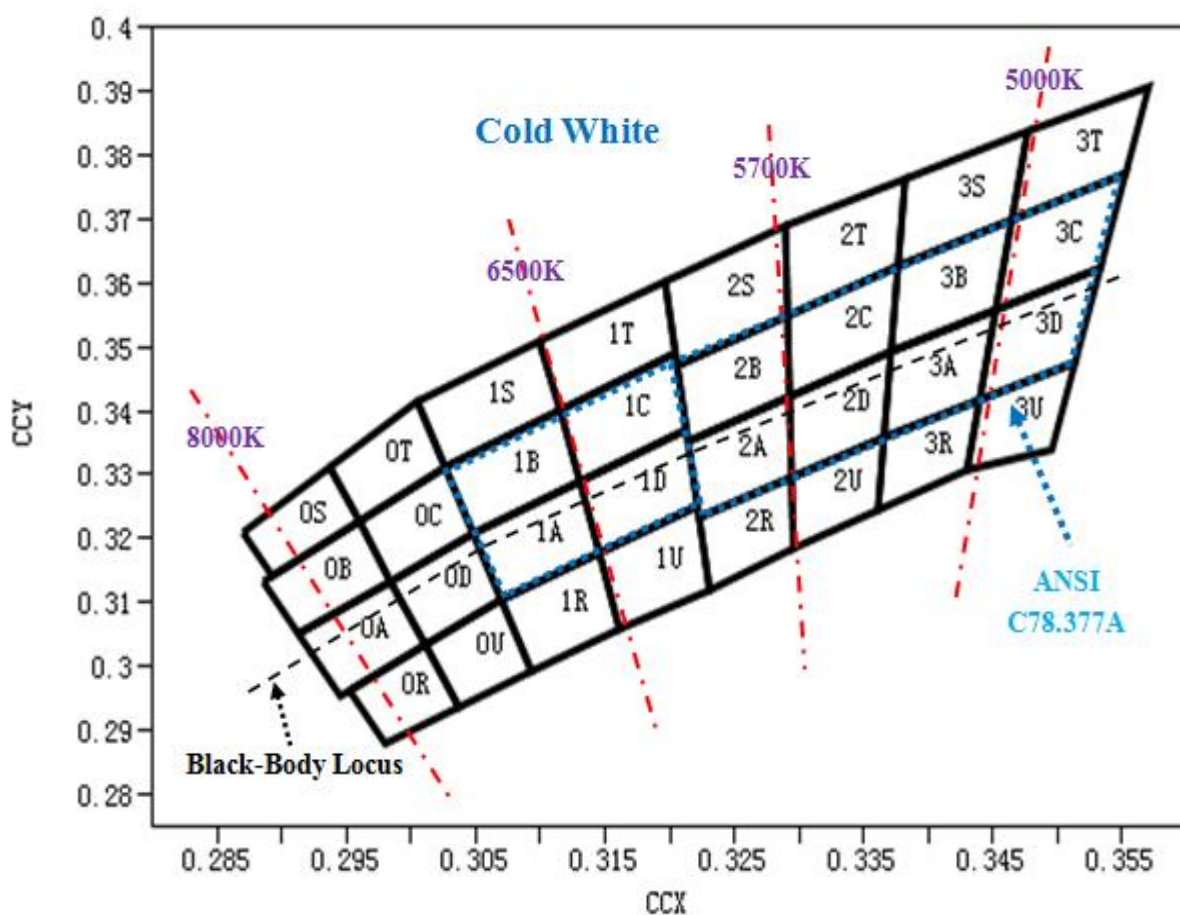
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Bins Regin

1.Color Bins



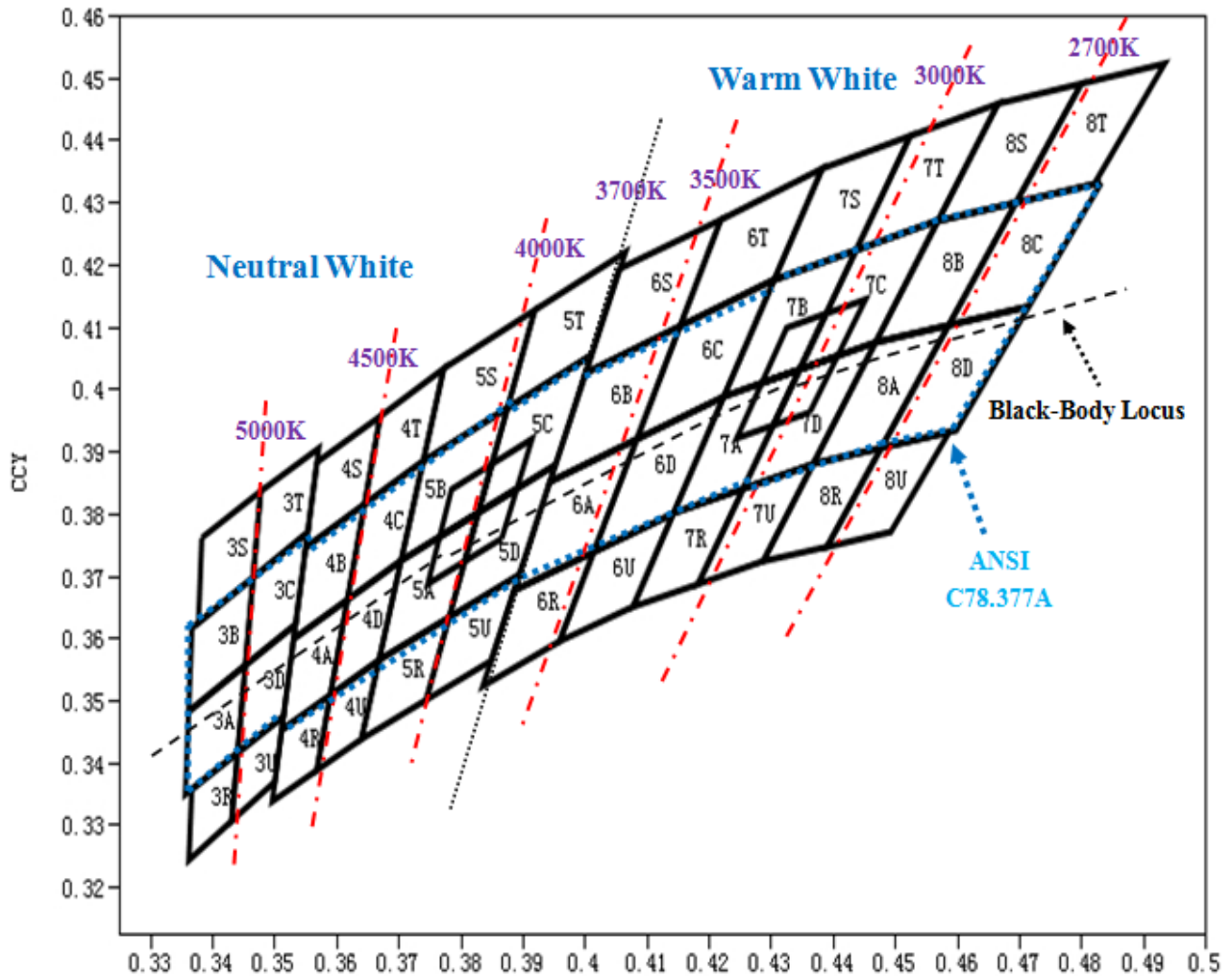
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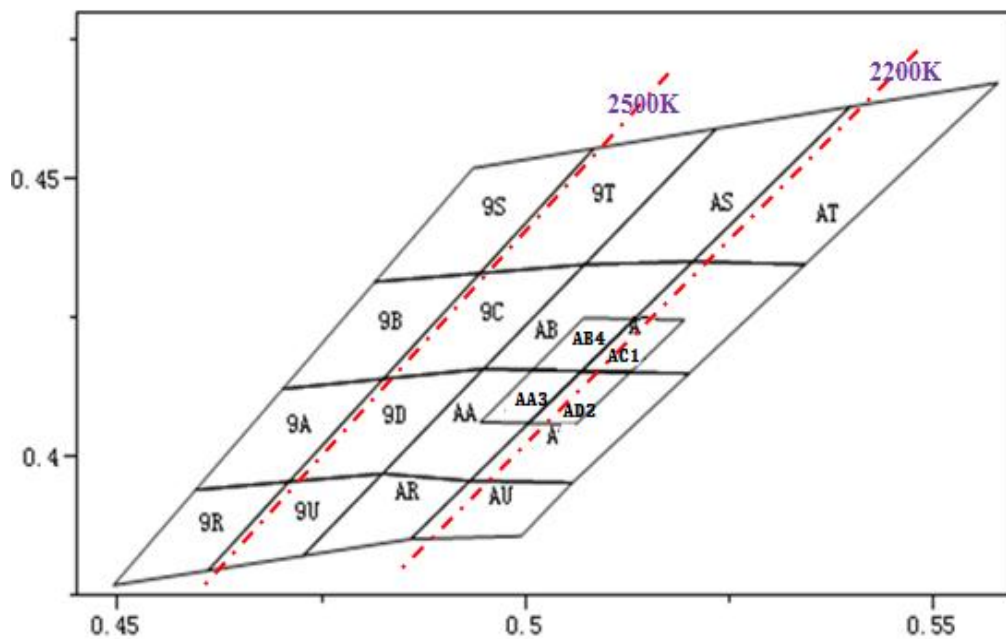
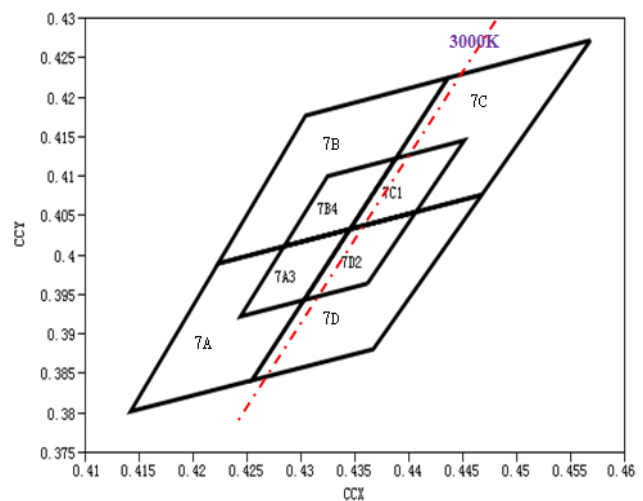
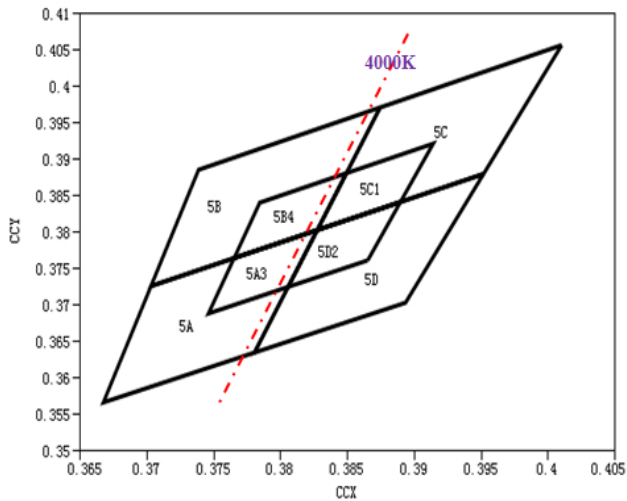
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Color Bins for 2200K, 3000K, 4000K



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The Chromaticity And Color Temperature Table(K)	
Typical Color Temperature	Chromaticity Areas
2200	AA、AB、AC、AD、AA、AB4、AC1、AD2
2500	9A、9B、9C、9D
2700	8A、8B、8C、8D
3000	7A0、7B0、7C0、7D0、7A3、7B4、7C1、7D2
3500	6A、6B、6C、6D
4000	5A0、5B0、5C0、5D0、5A3、5B4、5C1、5D2
4500	4A、4B、4C、4D、4R、4S、4T、4U
5000~5700	2C、2D、2T、2U、3A、3B、3R、3S
5700~6500	1C、1D、1T、1U、2A、2B、2R、2S
6500~8000	0A、0B、0C、0D、0R、0S、0U、0T、1A、1B、1R、1S

2.Luminance Bins

Bin	Min.	Max.	Condition
MB	250	270	T solder pad = 25°C IF=700 mA
NB	270	290	
PB	290	310	
QB	310	330	
RB	330	350	

Note: It maintains a tolerance of $\pm 7\%$ on luminous flux measurements.

3.CRI Bins

BIN	Range
60	60~100
70	70~100

Note: It maintains a tolerance of ± 2 on CRI measurements.

4.Voltage Bins

BIN	Range
B2	2.8-3.0
B3	3.0-3.2
B4	3.2-3.4
B5	3.4-3.6

Note: It maintains a tolerance of ± 0.05 on VF measurements.

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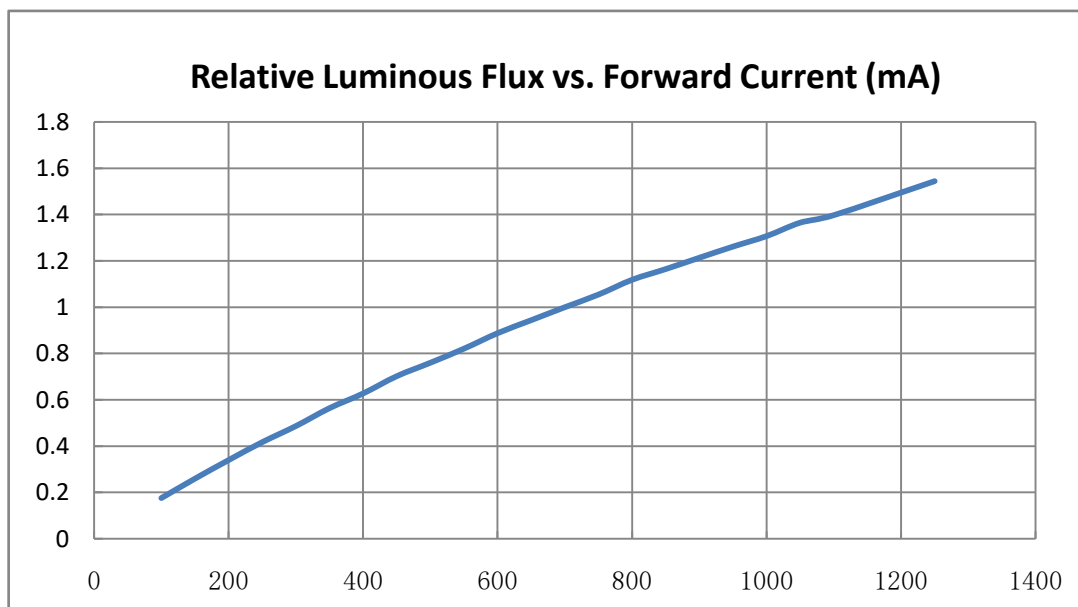
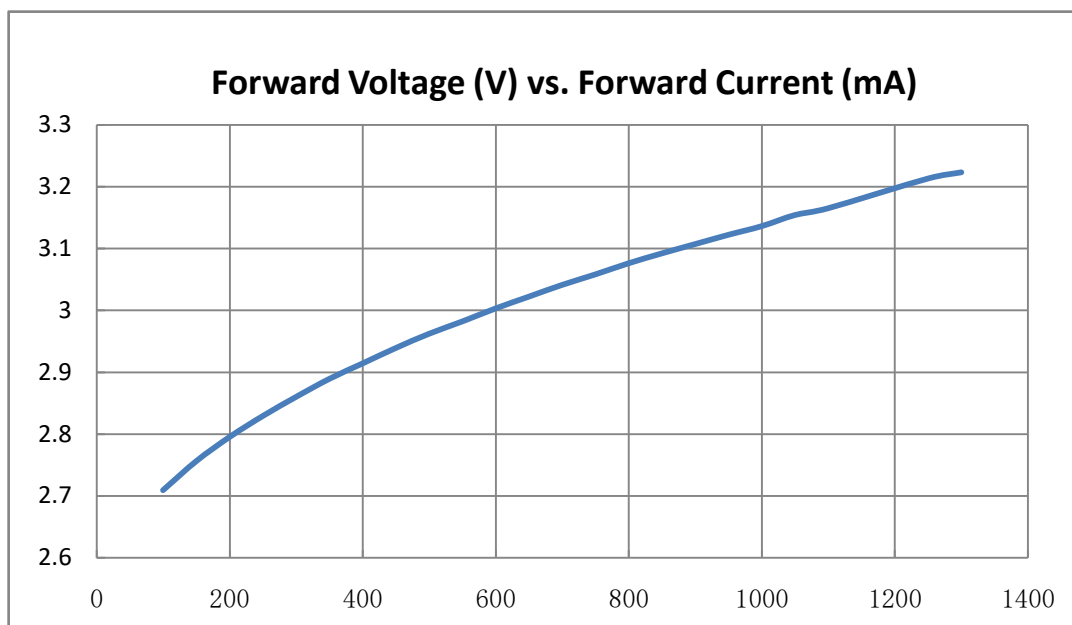
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The Photoelectric Characteristics Graph (T_j= 25 °C,6000K)

Safe use advised within the scope of photoelectric curve

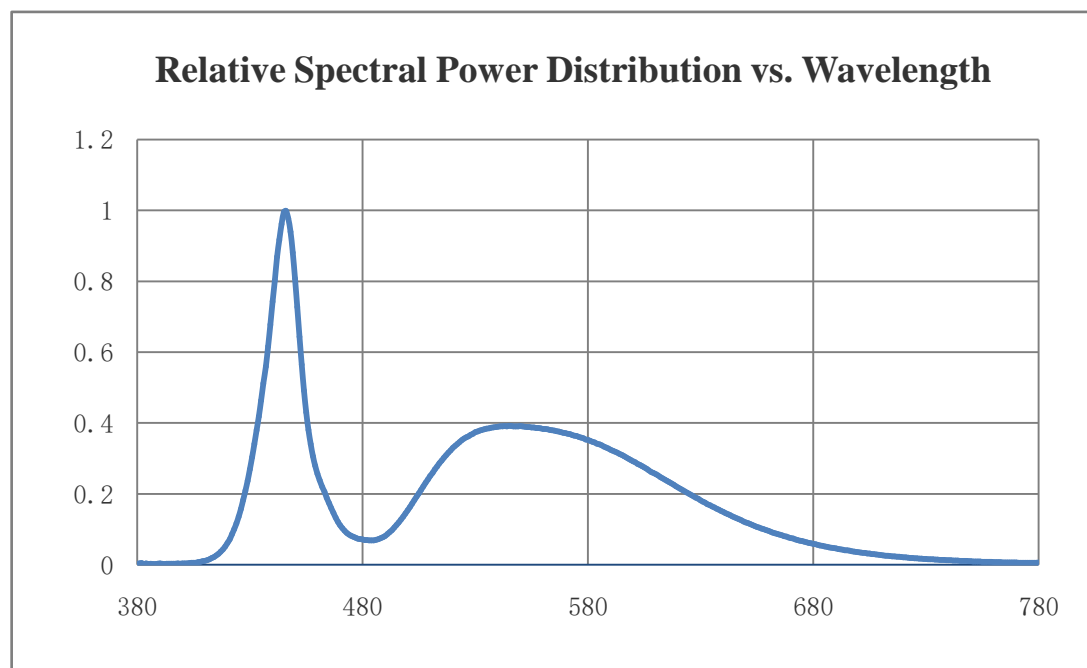
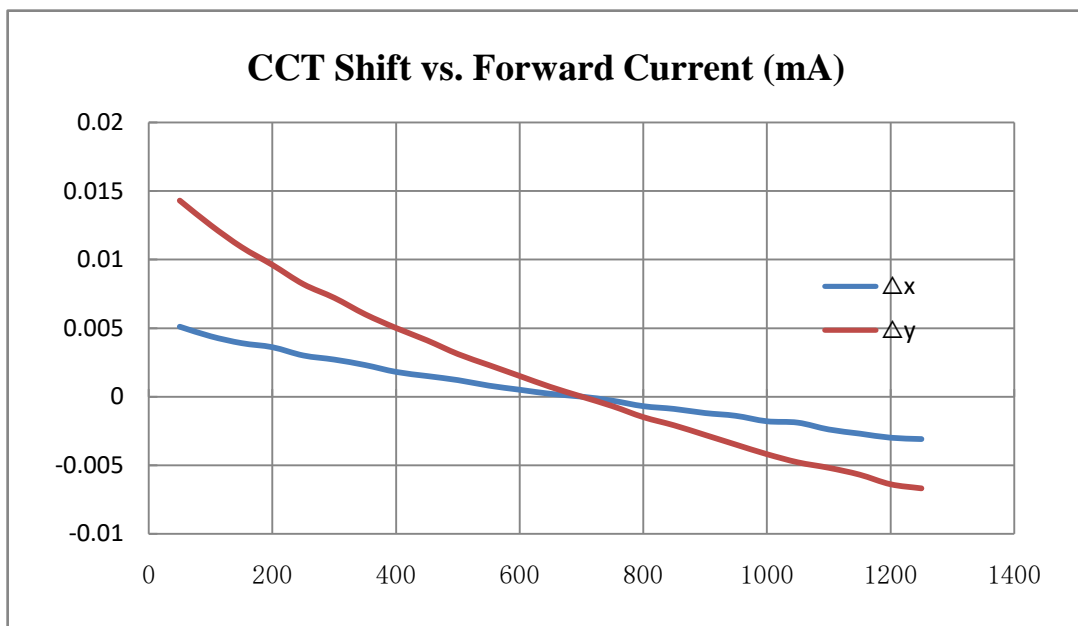


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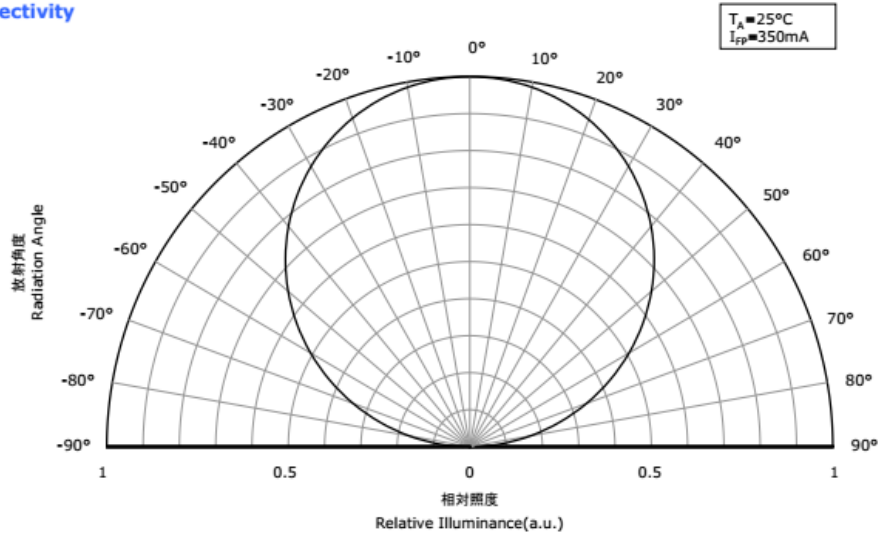
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All characteristics shown are for reference only and not guaranteed.

指向特性
Directivity



➤ The graphs above the characteristics for Ra70 LEDs of this product

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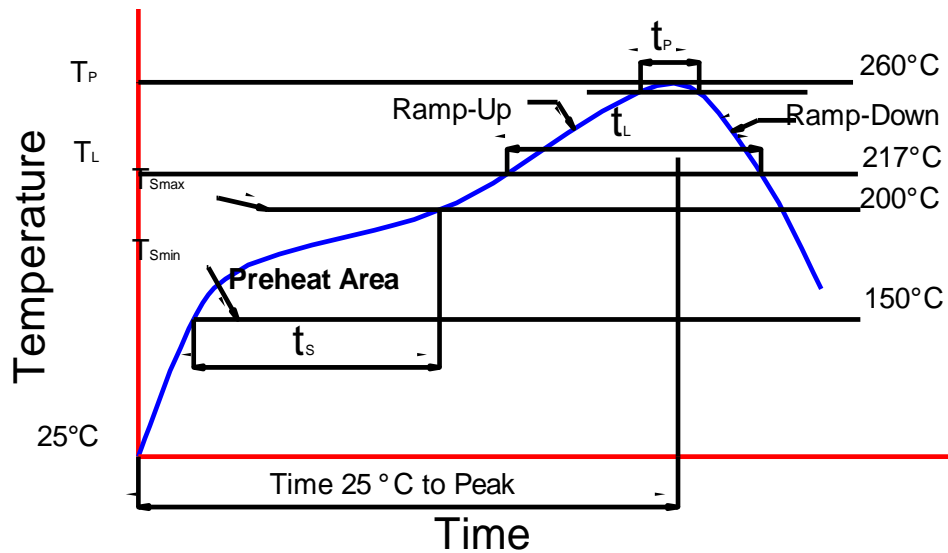
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Reflow Soldering Temperature Graph



Profile Feature	Lead-Free Solder
Average Ramp-Up Rate (T _{smax} to T _P)	3 °C/sec max.
Preheat:Temperature Min (T _{smin})	150
Preheat:Temperature Max (T _{smax})	200
Preheat:Time (t _{smin} to t _{smax})	60-120 secs
Time Maintained (T _L)	217°C
Time Maintained Above:Time (t _L)	60-150 secs
Peak/Classification	260°C
Time Within 5°C of Actual Peak	5 secs
Ramp-Down Rate	6°C/sec max.
Time 25 °C to Peak Temperature	8 minutes Max.

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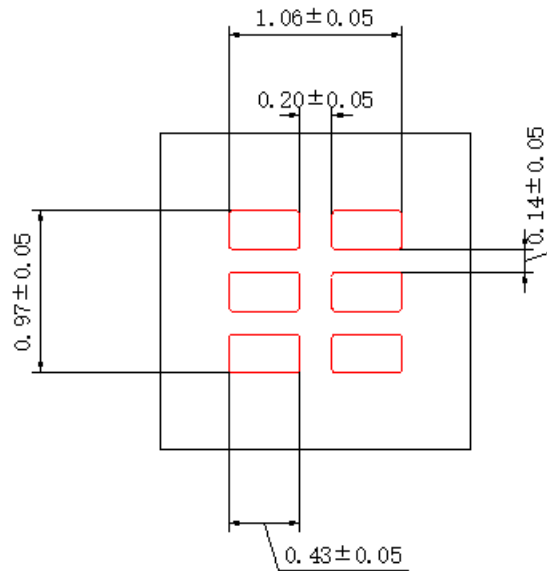
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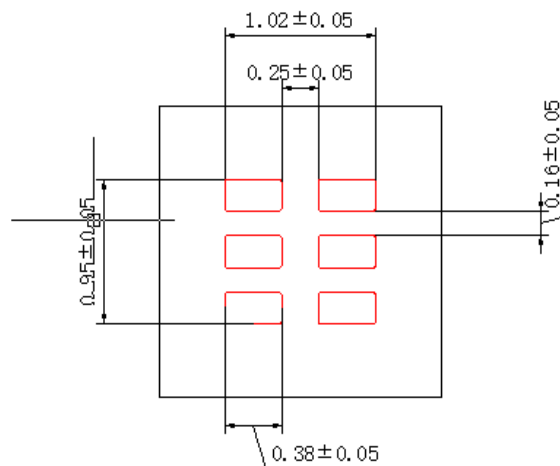
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PCB Pad Dimensions



Soldering Pad Design



Meter Solder Stencil Aperture

Unit: mm.

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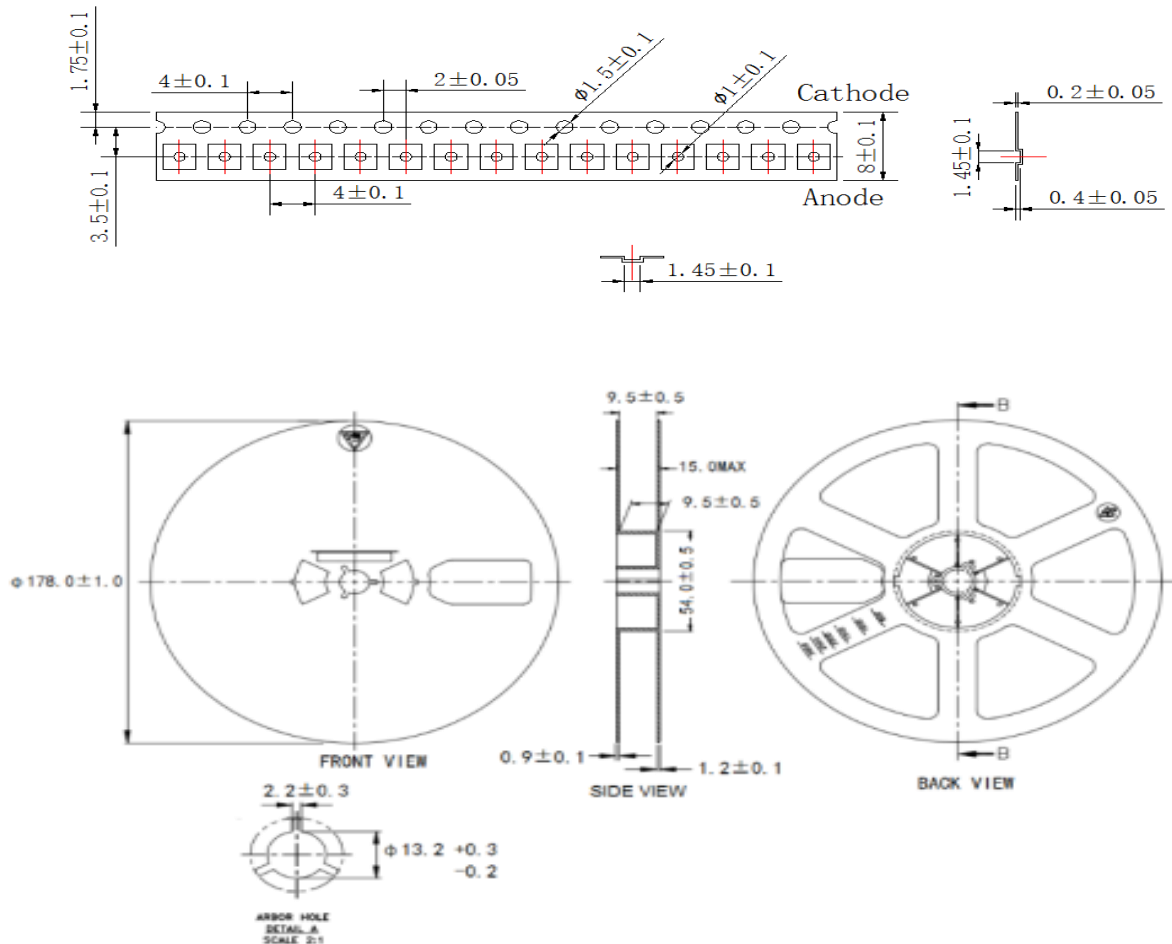
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Package Type

Unit: mm



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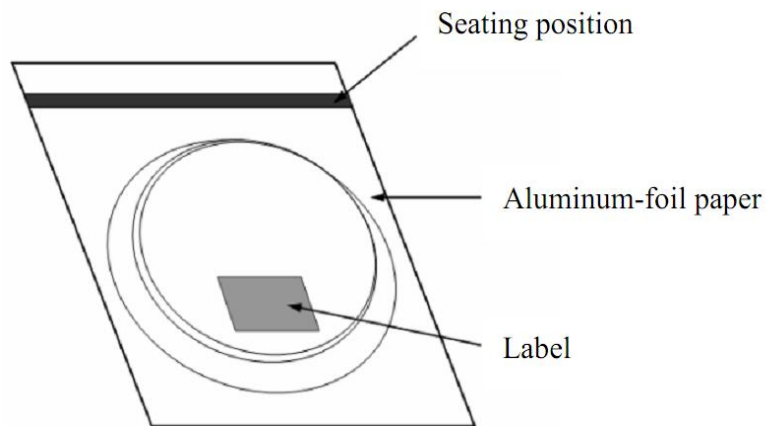
- Reelsize:6000pcs.
- The tape packing method complies with IJSC0806(Packing of Electronic Components on Continuous Tapes).
- When the tape is rewound due to work interruptions, no more than 10N should be applied to the embossed carrier tape. The LEDs may stick to the cover tape.

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Damp-Proof Packing



Label Explanation

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Reliability

(1) Tests and Results

Test	Reference Standard	Test Conditions	Test Duration	Failure Criteria#	Units Failed/Tested
Resistance to Soldering Heat(Reflow Soldering)	JEITAED=4701 300 301	$T_{sld}=260^{\circ}\text{C}$, 10sec, 2reflows, Precondition: 30°C , 70%RH, 4weeks.		#1	0/22
Solderability(Reflow Soldering)	JEITA ED=4701 303 303A	$T_{sld}=245\pm5^{\circ}\text{C}$, 5sec, Lead-free Solder(Sn-3.0Ag-0.5Cu)		#2	0/22
Temperature Cycle	JEITA ED=4701 100 105	-40°C (30min)~ 25°C (5min)~ 100°C (30min)~ 25°C (5min)	100cycles	#1	0/22
Moisture Resistance(Cyclic)	JEITA ED=4701 200 203	$25^{\circ}\text{C}\sim65^{\circ}\text{C}\sim-10^{\circ}\text{C}$, 90%RH, 24hr per cycle	10cycles	#1	0/22
High Temperature Storage	JEITA ED=4701 200 201	$T_A=100^{\circ}\text{C}$	1000 cycles	#1	0/22
Temperature Humidity Storage	JEITA ED=4701 100	$T_A=60^{\circ}\text{C}$, RH=90%	1000cycles	#1	0/22
Low Temperature Storage	JEITA ED=4701 200 202	$T_A=-40^{\circ}\text{C}$	1000 cycles	#1	0/22
Room Temperature Operating Life		$T_A=25^{\circ}\text{C}$, $I_F=1200\text{mA}$ Test board: See NOTES below	1000 cycles	#1	0/22
High Temperature Operating Life		$T_A=100^{\circ}\text{C}$, $I_F=1200\text{mA}$ Test board: See NOTES below	1000 cycles	#1	0/22
Temperature Humidity Operating Life		60°C , RH=90%, $I_F=1200\text{mA}$ Test board: See NOTES below	500cycles	#1	0/22
Low Temperature Operating Life		$T_A=-40^{\circ}\text{C}$, $I_F=1200\text{mA}$ Test board: See NOTES below	1000 cycles	#1	0/22
Vibration	JEITA ED=4701 400 403	200m/s^2 , 100~20000~100Hz, 4cycles, 4min, each X, Y, Z	48cycles	#1	0/22
Free Fall		3drops from a height of		#1	0/22

NOTES:

Test board: FR4 board thickness=1.6mm, copper layer thickness=35um, $R_{\theta JA}\approx 30^{\circ}\text{C/W}$

Measurement are performed after allowing the LEDs to return to room temperature.

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(2) Failure Criteria

Criteria #	Items	Conditions	Failure Criteria
#1	Forward Voltage (V_F)	$I_F=700\text{mA}$	> Initial value $\times 1.1$
	Luminous Flux (Φ_v)	$I_F=700\text{mA}$	> Initial value $\times 0.7$
	Reverse Current (I_R)	$V_R=5\text{V}$	> Initial value $\times 2.0$
#2	Solderability	-	Less than 95% solder

Cautions

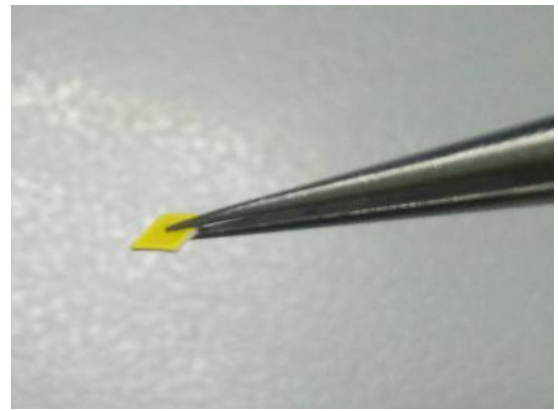
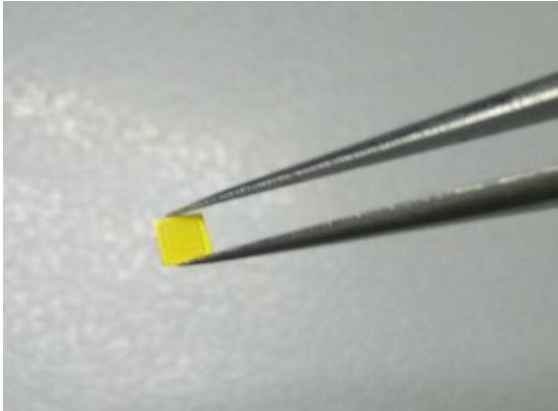
➤ Storage

Conditions		Temperature	Humidity	Time
Storage	Before Opening Aluminum Bag	$\leq 30^\circ\text{C}$	$\leq 90\%\text{RH}$	With in 1 Year for
	After Opening Aluminum Bag	$\leq 30^\circ\text{C}$	$\leq 70\%\text{RH}$	$\leq 4\text{weeks}$

- Do not place the chips in damp places, Storage temperature between -40°C and 100°C , Relative humidity under 85%.
- Don't touch any unknown liquid, In particular, acetone.
- Prevent electrostatic killed, Manual operation is required to wear rubber gloves and wear electrostatic ring.

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- Prevent all mechanical force, Using tweezers clip to clip side gently, not picking up electrode surface and fluorescent surface.



- In the process of welding, don't put any external pressure on the chips, otherwise the LED internal cracks may appear, this will cause quality problems.

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